

# DDR4 SDRAM RDIMM

## Addendum

### MTA18ASF4G72PZ – 32GB

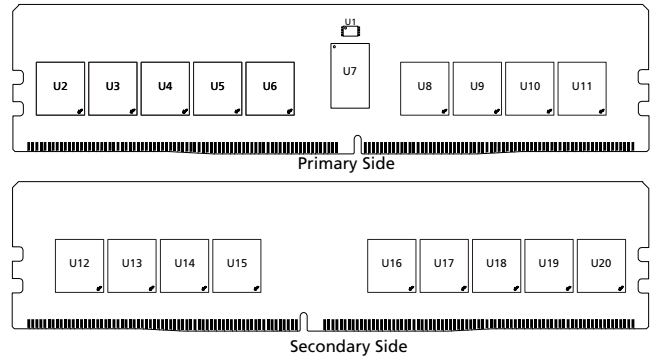
### Introduction

Information provided here is in addition to or supersedes information provided in the Micron DDR4 RDIMM Core data sheet.

### Features

- DDR4 functionality and operations supported as defined in the component data sheet
- Features and specifications defined in the Micron DDR4 RDIMM Core data sheet
- 288-pin, registered dual in-line memory module (RDIMM)
- Fast data transfer rates: PC4-3200, PC4-2933
- 32GB (4 Gig x 72)
- Single-rank
- 16 internal banks; 4 groups of 4 banks each

**Figure 1: 288-Pin RDIMM (MO-309, R/C-C3)**



### Options

- Operating temperature
  - Commercial ( $0^{\circ}\text{C} \leq T_{\text{OPER}} \leq 95^{\circ}\text{C}$ )
- Package
  - 288-pin DIMM (halogen-free)
- Frequency/CAS latency
  - 0.625ns @ CL = 22 (DDR4-3200)
  - 0.682ns @ CL = 21 (DDR4-2933)

### Marking

None  
 Z  
 -3G2  
 -2G9

**Table 1: Addressing**

Parameter	32GB
Row address	256K A[17:0]
Column address	1K A[9:0]
Device bank group address	4 BG[1:0]
Device bank address per group	4 BA[1:0]
Device configuration	16Gb (4 Gig x 4), 16 banks
Module rank address	1 CS0_n

**Table 2: Part Numbers and Timing Parameters – 32GB Modules**

Base device: MT40A4G4,<sup>1</sup> 16Gb DDR4 SDRAM

Part Number <sup>2</sup>	Module Density	Configuration	Module Bandwidth	Memory Clock/ Data Rate	Clock Cycles (CL-nRCD-nRP)
MTA18ASF4G72PZ-3G2__	32GB	4 Gig x 72	25.6 GB/s	0.625ns/3200 MT/s	22-22-22
MTA18ASF4G72PZ-2G9__	32GB	4 Gig x 72	23.47 GB/s	0.682/2933 MT/s	21-21-21

- Notes:
1. The data sheet for the base device can be found on [micron.com](http://micron.com).
  2. All part numbers end with a two-place code (not shown) that designates component and PCB revisions. Consult factory for current revision codes. Example: MTA18ASF4G72PZ-3G2B1.

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## DQ Map

Table 3: Component-to-Module DQ Map

Component Reference Number	Component DQ	Module DQ	Module Pin Number	Component Reference Number	Component DQ	Module DQ	Module Pin Number
U2	0	3	157	U3	0	11	168
	1	1	150		1	9	161
	2	2	12		2	10	23
	3	0	5		3	8	16
U4	0	19	179	U5	0	27	190
	1	17	172		1	25	183
	2	18	34		2	26	45
	3	16	27		3	24	38
U6	0	CB3	201	U8	0	35	249
	1	CB1	194		1	33	242
	2	CB2	56		2	34	104
	3	CB0	49		3	32	97
U9	0	43	260	U10	0	51	271
	1	41	253		1	49	264
	2	42	115		2	50	126
	3	40	108		3	48	119
U11	0	59	282	U12	0	60	128
	1	57	275		1	62	135
	2	58	137		2	61	273
	3	56	130		3	63	280
U13	0	52	117	U14	0	44	106
	1	54	124		1	46	113
	2	53	262		2	45	251
	3	55	269		3	47	258
U15	0	36	95	U16	0	CB4	47
	1	38	102		1	CB6	54
	2	37	240		2	CB5	192
	3	39	247		3	CB7	199
U17	0	28	36	U18	0	20	25
	1	30	43		1	22	32
	2	29	181		2	21	170
	3	31	188		3	23	177
U19	0	12	14	U20	0	4	3
	1	14	21		1	6	10
	2	13	159		2	5	148
	3	15	166		3	7	155



## I<sub>DD</sub> Specifications

**Table 4: DDR4 I<sub>DD</sub> Specifications and Conditions – 32GB (Die Revision E)**

Values are for the MT40A4G4 DDR4 SDRAM only and are computed from values specified in the 16Gb (4 Gig x 4) component data sheet.

Parameter	Symbol	3200	2933	Units
One bank ACTIVATE-PRECHARGE current	I <sub>DD0</sub>	990	972	mA
One bank ACTIVATE-PRECHARGE, word line boost, I <sub>pp</sub> current	I <sub>PP0</sub>	54	54	mA
One bank ACTIVATE-READ-PRECHARGE current	I <sub>DD1</sub>	1188	1170	mA
Precharge standby current	I <sub>DD2N</sub>	810	792	mA
Precharge standby ODT current	I <sub>DD2NT</sub>	918	900	mA
Precharge power-down current	I <sub>DD2P</sub>	684	684	mA
Precharge quiet standby current	I <sub>DD2Q</sub>	756	756	mA
Active standby current	I <sub>DD3N</sub>	1080	1062	mA
Active standby I <sub>pp</sub> current	I <sub>PP3N</sub>	36	36	mA
Active power-down current	I <sub>DD3P</sub>	864	846	mA
Burst read current	I <sub>DD4R</sub>	2286	2142	mA
Burst write current	I <sub>DD4W</sub>	1890	1818	mA
Burst refresh current (1x REF)	I <sub>DD5R</sub>	1224	1224	mA
Burst refresh I <sub>pp</sub> current (1x REF)	I <sub>PP5R</sub>	72	72	mA
Self refresh current: Normal temperature range (0°C to 85°C)	I <sub>DD6N</sub>	954	954	mA
Self refresh current: Extended temperature range (0°C to 95°C)	I <sub>DD6E</sub>	2034	2034	mA
Self refresh current: Reduced temperature range (0°C to 45°C)	I <sub>DD6R</sub>	360	360	mA
Auto self refresh current (25°C)	I <sub>DD6A</sub>	198	198	mA
Auto self refresh current (45°C)	I <sub>DD6A</sub>	360	360	mA
Auto self refresh current (75°C)	I <sub>DD6A</sub>	918	918	mA
Auto self refresh current (95°C)	I <sub>DD6A</sub>	2034	2034	mA
Auto self refresh I <sub>pp</sub> current	I <sub>PP6X</sub>	108	108	mA
Bank interleave read current	I <sub>DD7</sub>	3546	3510	mA
Bank interleave read I <sub>pp</sub> current	I <sub>PP7</sub>	162	162	mA
Maximum power-down current	I <sub>DD8</sub>	648	648	mA



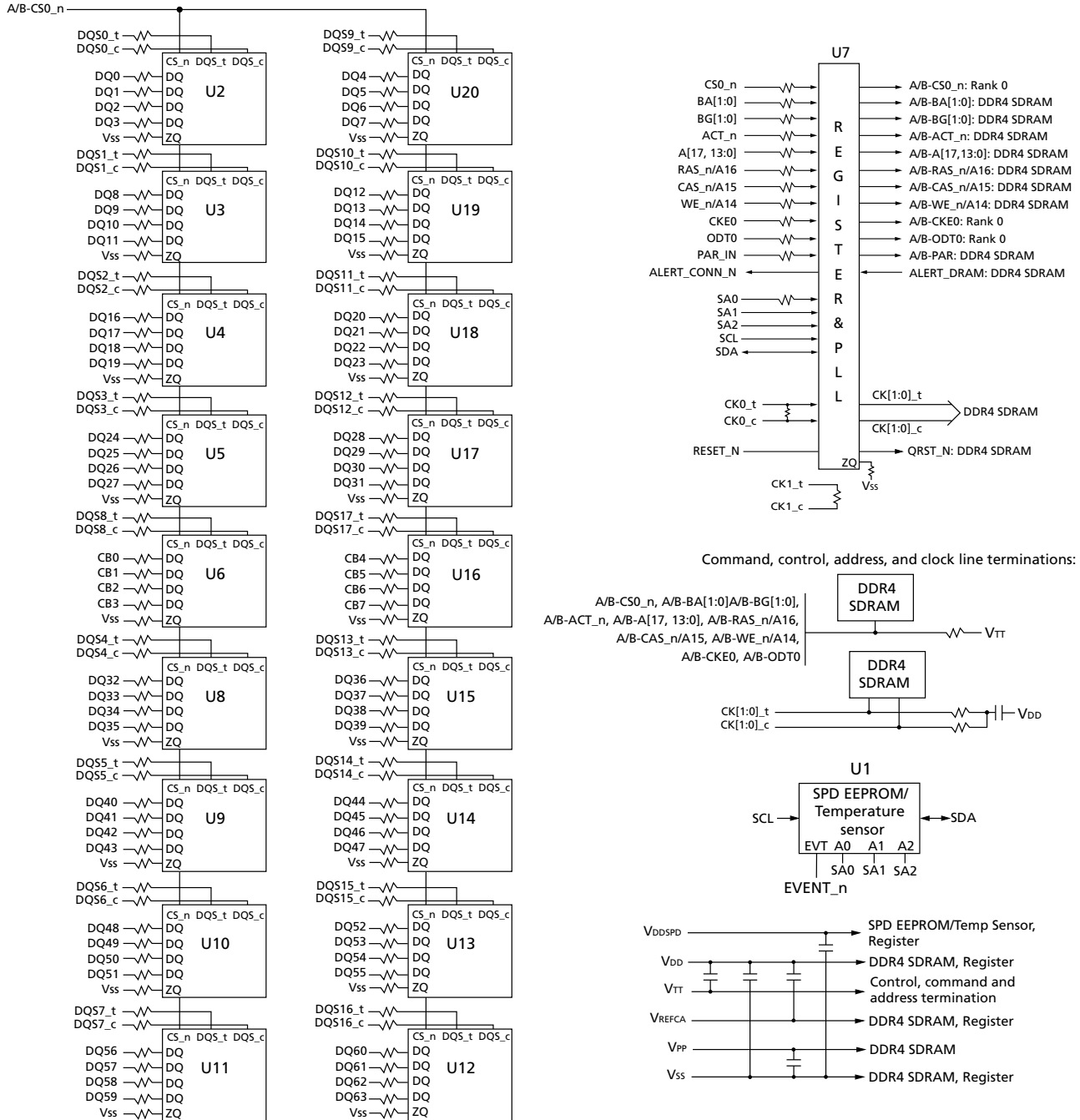
**Table 5: DDR4 I<sub>DD</sub> Specifications and Conditions – 32GB (Die Revision B)**

Values are for the MT40A4G4 DDR4 SDRAM only and are computed from values specified in the 16Gb (4 Gig x 4) component data sheet.

Parameter	Symbol	3200	2933	Units
One bank ACTIVATE-PRECHARGE current	I <sub>DD0</sub>	1080	1062	mA
One bank ACTIVATE-PRECHARGE, word line boost, I <sub>pp</sub> current	I <sub>pp0</sub>	72	72	mA
One bank ACTIVATE-READ-PRECHARGE current	I <sub>DD1</sub>	1260	1242	mA
Precharge standby current	I <sub>DD2N</sub>	936	918	mA
Precharge standby ODT current	I <sub>DD2NT</sub>	1008	990	mA
Precharge power-down current	I <sub>DD2P</sub>	774	774	mA
Precharge quite standby current	I <sub>DD2Q</sub>	846	846	mA
Active standby current	I <sub>DD3N</sub>	1404	1386	mA
Active standby I <sub>pp</sub> current	I <sub>pp3N</sub>	54	54	mA
Active power-down current	I <sub>DD3P</sub>	1242	1224	mA
Burst read current	I <sub>DD4R</sub>	3096	2952	mA
Burst write current	I <sub>DD4W</sub>	2952	2826	mA
Burst refresh current (1x REF)	I <sub>DD5R</sub>	1422	1404	mA
Burst refresh I <sub>pp</sub> current (1x REF)	I <sub>pp5R</sub>	90	90	mA
Self refresh current: Normal temperature range (0°C to 85°C)	I <sub>DD6N</sub>	1206	1206	mA
Self refresh current: Extended temperature range (0°C to 95°C)	I <sub>DD6E</sub>	2178	2178	mA
Self refresh current: Reduced temperature range (0°C to 45°C)	I <sub>DD6R</sub>	522	522	mA
Auto self refresh current (25°C)	I <sub>DD6A</sub>	180	180	mA
Auto self refresh current (45°C)	I <sub>DD6A</sub>	522	522	mA
Auto self refresh current (75°C)	I <sub>DD6A</sub>	1098	1098	mA
Auto self refresh current (95°C)	I <sub>DD6A</sub>	2178	2178	mA
Auto self refresh I <sub>pp</sub> current	I <sub>pp6X</sub>	198	198	mA
Bank interleave read current	I <sub>DD7</sub>	4284	4158	mA
Bank interleave read I <sub>pp</sub> current	I <sub>pp7</sub>	198	198	mA
Maximum power-down current	I <sub>DD8</sub>	720	720	mA

## Functional Block Diagram

Figure 2: Functional Block Diagram



Note: 1. The ZQ ball on each DDR4 component is connected to an external 240Ω ±1% resistor that is tied to ground. It is used for the calibration of the component's ODT and output driver.



## 32GB (x72, ECC, SR) 288-Pin DDR4 RDIMM Functional Block Diagram

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8000 S. Federal Way, P.O. Box 6, Boise, ID 83707-0006, Tel: 208-368-4000  
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Although considered final, these specifications are subject to change, as further product development and data characterization some-  
times occur.